# **SKN 141F**



### **Stud Diode**

Fast Recovery Rectifier Diode

SKN 141F SKR 141F

#### **Features**

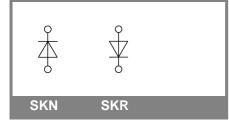
- Small recovered charge
- Soft recovery
- Hermetic metal case with glass insulator
- Threaded stud M12
- SKN: anode to stud; SKR: cathode to stud

### **Typical Applications**

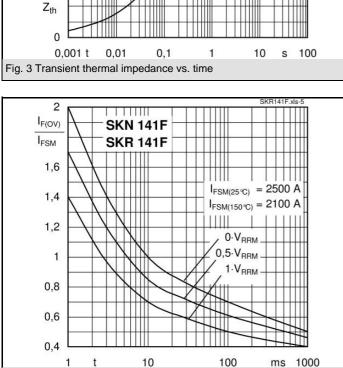
- Inverse diode for GTO and asymmetric thyristor
- Inverters and choppers
- A.C. motor control
- Uniterruptible power supplies
  (UPS)

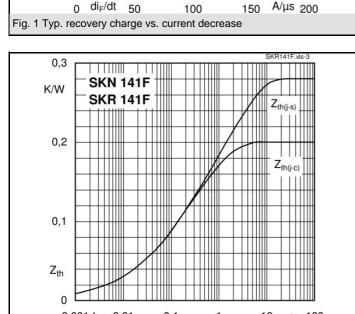
V <sub>RSM</sub>	V <sub>RRM</sub>	I <sub>FRMS</sub> = 260 A (maximum value for continuous operation)		
V	V	I <sub>FAV</sub> = 140 A (sin. 180; 1000 Hz; T <sub>c</sub> = 100 °C)		°C)
1200	1200	SKN 141F12	SKR 141F12	
1400	1400	SKN 141F14	SKR 141F14	
1500	1500	SKN 141F15	SKR 141F15	
1700	1700	SKN 141F17	SKR 141F17	

Symbol	Conditions	Values	Units
I <sub>FAV</sub>	sin. 180; T <sub>c</sub> = 85 (100) °C	168 (140)	А
I <sub>FAV</sub>	K1,1F; T <sub>a</sub> = 35 °C; sin. 180; 1000 Hz	114	А
I <sub>FSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	2500	Α
	T <sub>vi</sub> = 150 °C; 10 ms	2100	А
i²t	T <sub>vj</sub> = 25 °C; 8,3 10 ms	31000	A²s
	T <sub>vj</sub> = 150 °C; 8,3 10 ms	22000	A²s
V <sub>F</sub>	T <sub>vi</sub> = 25 °C; I <sub>F</sub> = 300 A	max. 1,8	V
V <sub>(TO)</sub>	T <sub>vj</sub> = 150 °C	max. 1,1	V
r <sub>T</sub>	T <sub>vj</sub> = 150 °C	max. 2	mΩ
I <sub>RD</sub>	$T_{vj} = 25 \text{ °C}; V_{RD} = V_{RRM}$	max. 1	mA
I <sub>RD</sub>	$T_{vj}$ = 150 °C, $V_{RD}$ = $V_{RRM}$	max. 100	mA
Q <sub>rr</sub>	T <sub>vi</sub> = 150 °C, I <sub>F</sub> = 100 A,	90	μC
I <sub>RM</sub>	-di/dt = 100 A/µs, V <sub>R</sub> = 400 V	90	А
t <sub>rr</sub>		2000	ns
E <sub>rr</sub>		-	mJ
R <sub>th(j-c)</sub>		0,2	K/W
R <sub>th(c-s)</sub>		0,08	K/W
T <sub>vj</sub>		- 40 + 150	°C
T <sub>stg</sub>		- 55 + 150	°C
V <sub>isol</sub>		-	V~
M <sub>s</sub>	to heatsink	10	Nm
а		5 * 9,81	m/s²
m	approx.	100	g
Case		E 31	









200

μC

160

140

120

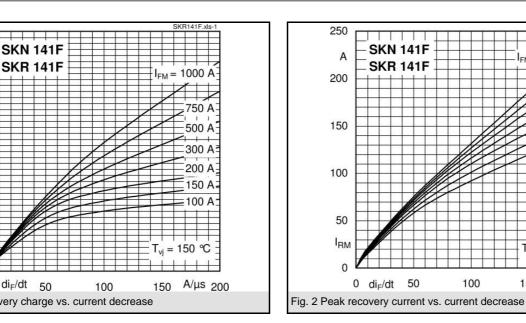
100

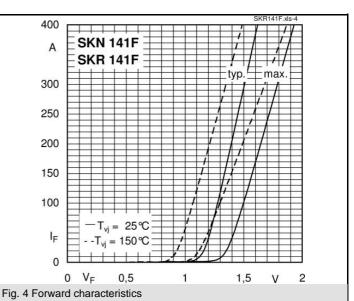
80

60

40 Qrr

0





100

 $I_{FM} = 1000 A_{2}$ 

750 A

500 A

350 A

200 A

150 A

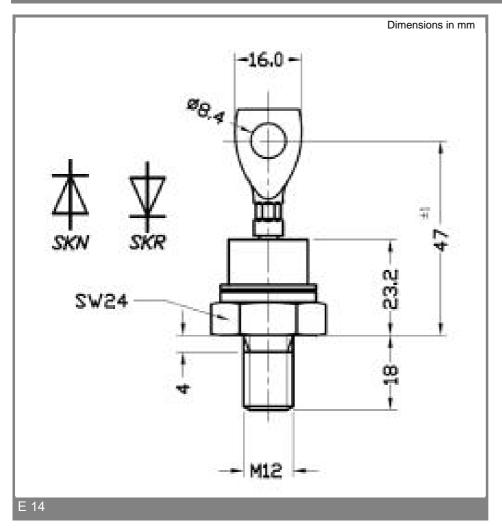
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T<sub>vj</sub> = 150 °C

150 A/µs 200

Fig. 5 Surge overload current vs. time

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